

Vishay High Power Products

Phase Control SCR TO-220AB FULL-PAK, 16 A

(A) O

TO-220AB FULL-PAK

1 (K)	(G) 3
-------	-------

PRODUCT SUMMARY				
V _T at 10 A	1.4 V			
I _{TSM}	200 A			
V _{RRM}	800/1200 V			

DESCRIPTION/FEATURES

The 16TTS..FP High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

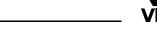
Fully isolated package (V_{INS} = 2500 V_{RMS}) is UL E78996 approved

This product has been designed and qualified for industrial level.

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS			
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C, common heatsink of 1 °C/W	13.5	17	А	

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I _{T(AV)}	Sinusoidal waveform	10	A		
I _{RMS}		16	A		
V _{DRM} /V _{RRM}		800/1200	V		
I _{TSM}		200	А		
V _T	10 A, T _J = 25 °C	1.4	V		
dV/dt		500	V/µs		
dl/dt		150	A/µs		
T _J	Range	- 40 to 125	°C		

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA		
16TTS08FP	800	800	10		
16TTS12FP	1200	1200	10		



Vishay High Power Products Phase Control SCR TO-220AB FULL-PAK, 16 A

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
		TEST CONDITIONS	TYP. MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	$T_c = 95$ °C, 180° conduction, half sine wave	10	
Maximum RMS on-state current	I _{RMS}		16	Α
Maximum peak, one-cycle,	ı	10 ms sine pulse, rated V _{RRM} applied	170	^
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	200	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	144	A ² s
Maximum 1-t for fusing	I ^ t	10 ms sine pulse, no voltage reapplied	200	A-S
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied	2000	A²√s
Maximum on-state voltage drop	V_{TM}	10 A, T _J = 25 °C	1.4	V
On-state slope resistance	r _t	T 105 °C	24.0	mΩ
Threshold voltage	V _{T(TO)}	T _J = 125 °C	1.1	V
Maximum various and direct lacks as a surrent	1 /1	T _J = 25 °C	0.5	
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	$T_J = 25 ^{\circ}\text{C}$ $V_R = \text{Rated V}_{RRM}/V_{DRM}$	10	
Holding current	I _H	Anode supply = 6 V, resistive load, initial I _T = 1 A 16TTS08FP, 16TTS12FP	- 100	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load	200	
Maximum rate of rise of off-state voltage	dV/dt		500	V/µs
Maximum rate of rise of turned-on current	dl/dt		150	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	w
Maximum average gate power	P _{G(AV)}		2.0	VV
Maximum peak positive gate current	+ I _{GM}		1.5	Α
Maximum peak negative gate voltage	- V _{GM}		10	V
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	90	mA
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	60	
		Anode supply = 6 V, resistive load, T _J = 125 °C	35	
		Anode supply = 6 V, resistive load, T _J = - 10 °C	3.0	
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	V
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V
Maximum DC gate voltage not to trigger	V_{GD}	T = 105 °C V = Poted value	0.2	
Maximum DC gate current not to trigger	I _{GD}	$T_J = 125$ °C, $V_{DRM} = Rated value$ 2.0		mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T _{.I} = 125 °C	4	μs
Typical turn-off time	tq	1 1 1 2 5 6	110	



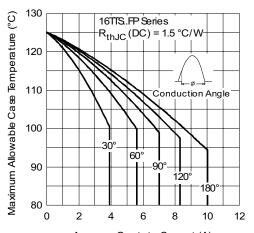
Phase Control SCR Vishay High Power Products TO-220AB FULL-PAK, 16 A

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.5		
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	1.5		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque ——	minimum			6 (5)	kgf · cm	
	maximum			12 (10)	(lbf ⋅ in)	
Marking device			Case style TO-220AB FULL-PAK (94/V0)	16TTS	16TTS08FP	
				16TTS	12FP	

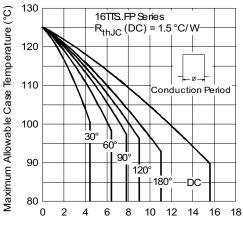
Vishay High Power Products

Phase Control SCR TO-220AB FULL-PAK, 16 A

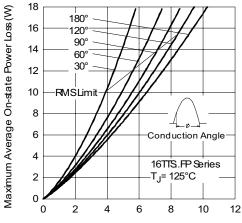




Average On-state Current (A) - Current Rating Characteristics



Average On-state Current (A) Fig. 2 - Current Rating Characteristics



Average On-state Current (A) - On-State Power Loss Characteristics

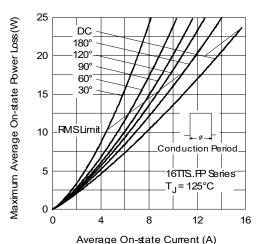
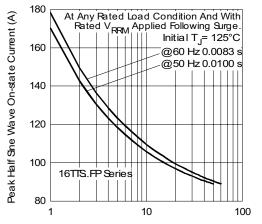
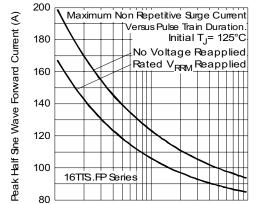


Fig. 4 - On-State Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N) Fig. 5 - Maximum Non-Repetitive Surge Current



0.01

0.1 Pulse Train Duration (s) Fig. 6 - Maximum Non-Repetitive Surge Current



Phase Control SCR Vishay High Power Products TO-220AB FULL-PAK, 16 A

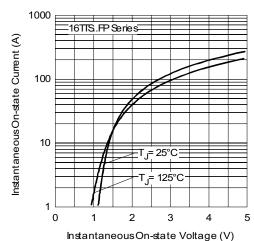


Fig. 7 - On-State Voltage Drop Characteristics

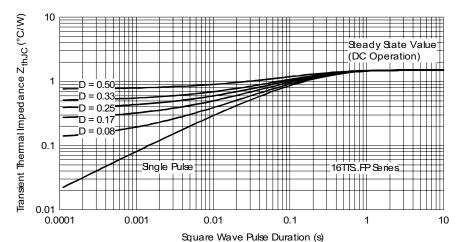
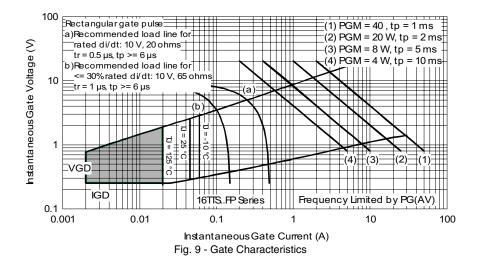


Fig. 8 - Thermal impedance Z_{thJC} Characteristics



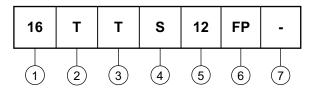
Vishay High Power Products

Phase Control SCR TO-220AB FULL-PAK, 16 A



ORDERING INFORMATION TABLE

Device code



- 1 Current rating, RMS value
- 2 Circuit configuration:

T = Single thyristor

3 - Package:

T = TO-220AB

4 - Type of silicon:

S = Converter grade

5 - Voltage code x 100 = V_{RRM} —

08 = 800 V 12 = 1200 V

6 - FULL-PAK

7 - • None = Standard production

• PbF = Lead (Pb)-free

Note: For higher voltage up to 1600 V contact factory

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95072				
Part marking information	http://www.vishay.com/doc?95069			



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com